**Product data sheet** 

## 1. General description

Ultrafast power diode in a SOD113 (TO-220F) plastic package.

## 2. Features and benefits

- · Low on-state loss
- Ultra low leakage
- · Low switching loss
- Fast switching
- · Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

## 3. Applications

- Home appliance power supply
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>h</sub> ≤ 71 °C; square-wave; Fig. 1; Fig. 2; Fig. 3	-	-	15	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; $T_h \le 71$ °C; square-wave	-	-	30	Α
1 0111	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sinusoidal waveform; Fig. 4	-	-	150	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sinusoidal waveform	-	-	165	Α
Static characte	eristics					
$V_{F}$	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.1	1.38	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 125 °C; <u>Fig. 6</u>	-	0.96	1.25	V
Dynamic chara	acteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{}$	-	50	60	ns

# **5. Pinning information**

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	K — A
2	Α	anode		001aaa020
mb	n.c.	mounting base; isolated	TO-220F (SOD113)	

# 6. Ordering information

### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
BYT79X-600P	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

## 7. Marking

### **Table 4. Marking codes**

Type number	Marking code
BYT79X-600P	BYT79X-600P

## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
$V_{RWM}$	crest working reverse voltage		-	600	V
$V_R$	reverse voltage	Square-wave; δ = 1.0	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>h</sub> $\leq$ 71 °C; square-wave; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	15	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; t <sub>p</sub> = 25 µs; T <sub>h</sub> ≤ 71 °C; squarewave	-	30	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sinusoidal waveform; Fig. 4	-	150	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sinusoidal waveform	-	165	Α
T <sub>stg</sub>	storage temperature		-65	175	°C
T <sub>j</sub>	junction temperature		-	175	°C

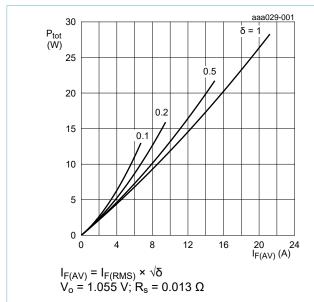


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

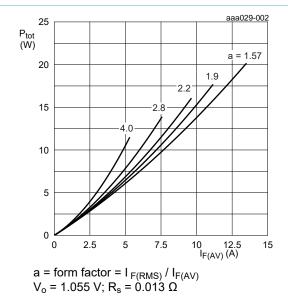


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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### Ultrafast recovery diode

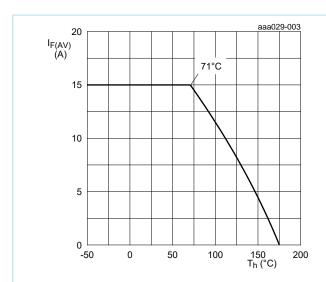


Fig. 3. Forward current as a function of heatsink temperature; maximum values

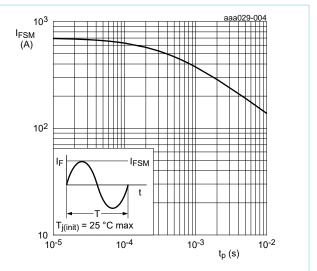
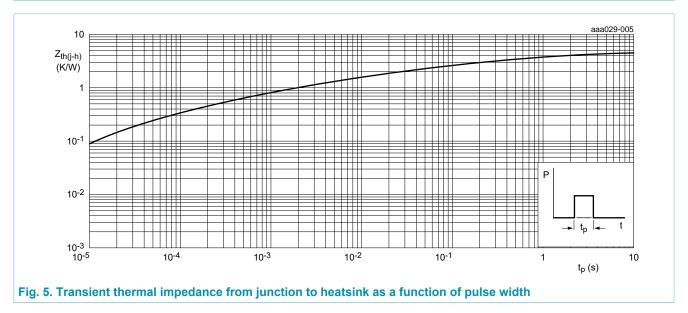


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-h)</sub>	thermal resistance from junction to heatsink	with heatsink compound; Fig. 5	-	-	4.8	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



### 10. Isolation characteristics

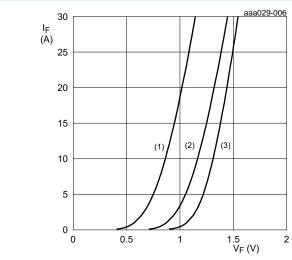
#### Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>isol(RMS)</sub>	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C <sub>isol</sub>	isolation capacitance	from cathode to external heatsink	-	10	-	pF

## 11. Characteristics

#### **Table 8. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.1	1.38	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 125 °C; <u>Fig. 6</u>	-	0.96	1.25	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	1	10	μΑ
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 125 °C	-	80	200	μΑ
Dynamic ch	naracteristics					
Q <sub>r</sub>	recovered charge	$I_F = 2 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 20 \text{ A/}\mu\text{s}$ ; Fig. 7	-	60	110	nC
		I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 100 A/μs;	- (	60	-	nC
t <sub>rr</sub>	reverse recovery time	T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	50	60	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/µs}$ ; $T_i = 100 \text{ °C}$	-	3	-	Α



 $V_o$  = 1.055 V;  $R_s$  = 0.013 Ω (1)  $T_j$  = 125 °C; typical values (2)  $T_j$  = 125 °C; maximum values (3)  $T_j$  = 25 °C; maximum values



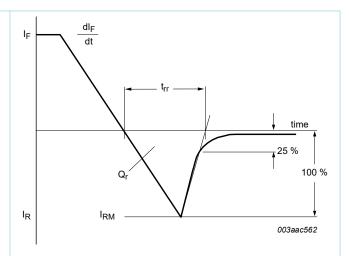
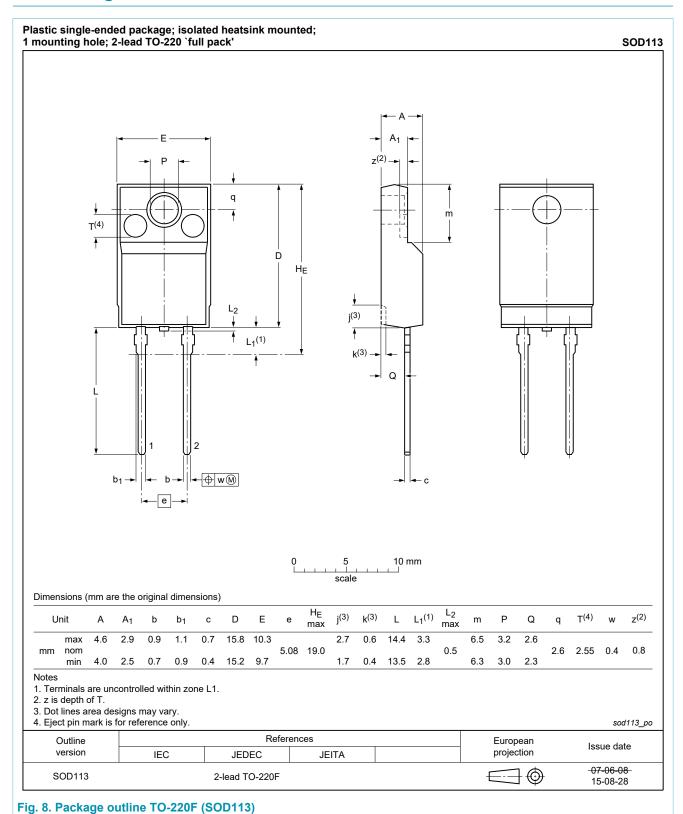


Fig. 7. Reverse recovery definitions; ramp recovery

## 12. Package outline



## 13. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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